

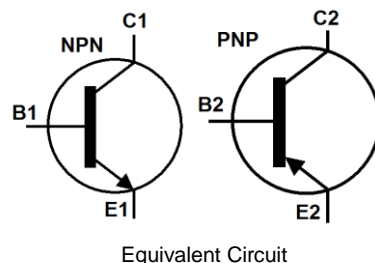
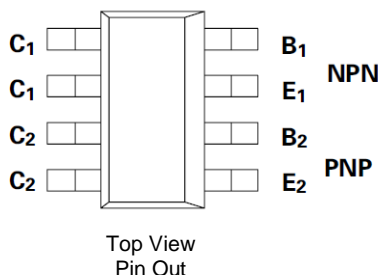
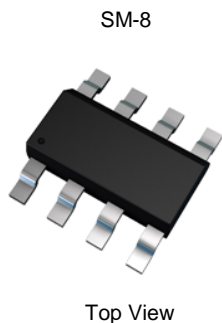
COMPLEMENTARY MEDIUM POWER HIGH GAIN TRANSISTOR IN SM-8 PACKAGE

Features

- NPN Transistor
 - $BV_{CEO} > 45$
 - $V_{CE(sat)} < 100mV @ I_C = 100mA$
 - Continuous Current $I_C = 2A$
- PNP Transistor
 - $BV_{CEO} > -40V$
 - $V_{CE(sat)} < -250mV @ I_C = -500mA$
 - Continuous Current $I_C = -2A$
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: SM-8 (8 LEAD SOT223)
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.117 grams (Approximate)

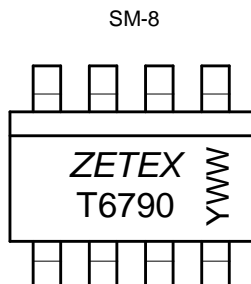


Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZDT6790TA	T6790	7	12	1,000
ZDT6790TC	T6790	13	12	4,000

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



T6790 = Product Type Marking Code
 YWW = Date Code Marking
 Y or \bar{Y} = Last Digit of Year (ex: 5= 2015)
 WW or $\bar{W}W$ = Week Code (01~53)

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	NPN	PNP	Unit
Collector-Base Voltage	V _{CB0}	45	-50	V
Collector-Emitter Voltage	V _{CEO}	45	-40	V
Emitter-Base Voltage	V _{EBO}	7	-7	V
Continuous Collector Current	I _C	2	-2	A
Peak Pulse Current (Note 5)	I _{CM}	6	-6	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

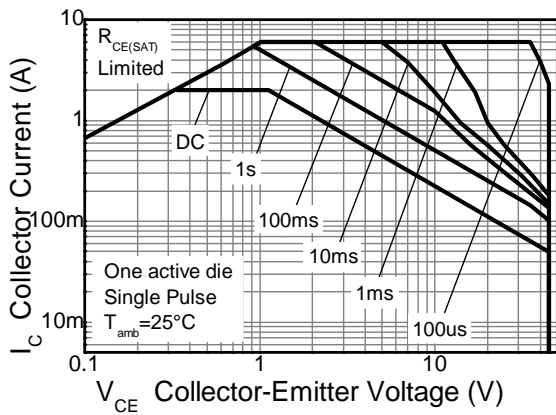
Characteristic	Symbol	Value	Unit
Collector Power Dissipation	P _D	(Note 5)	2.25
		(Note 6)	2.75
Thermal Resistance, Junction to Ambient	R _{θJA}	(Note 5)	55.60
		(Note 6)	45.50
Thermal Resistance, Junction to Leads	R _{θJL}	30.68	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 8)

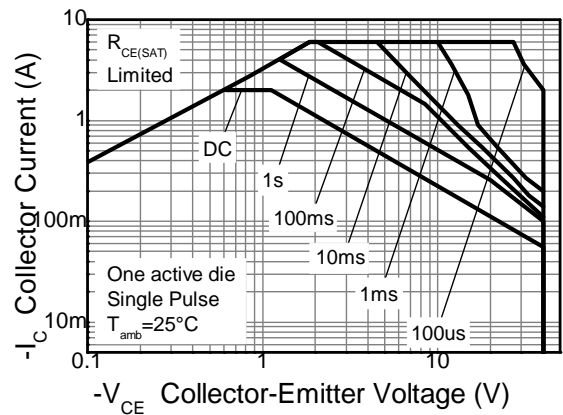
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
5. For a device with any single die active and mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
 6. Same as Note 5, except both die are active and equally sharing power.
 7. Thermal resistance from junction to solder-point (at the end of the collector lead).
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

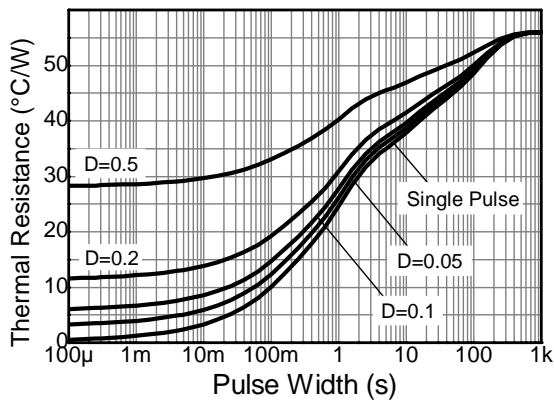
Thermal Characteristics and Derating Information



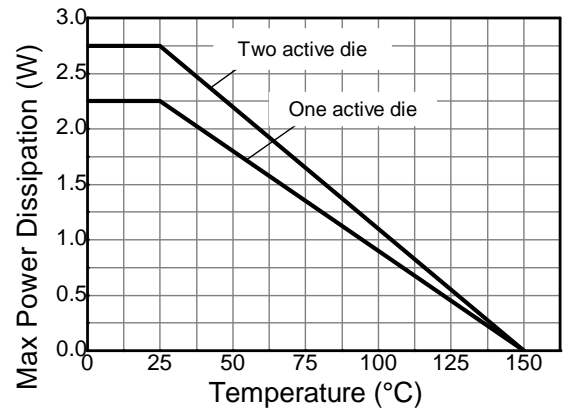
NPN Safe Operating Area



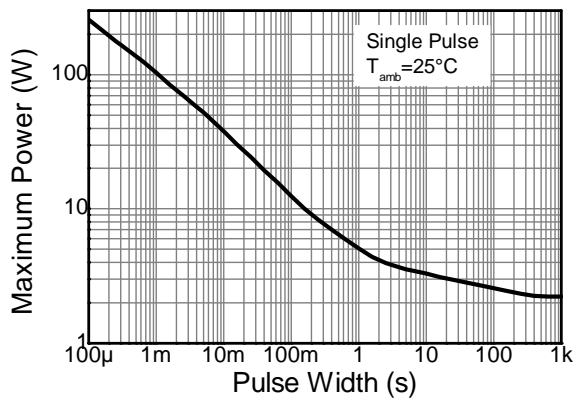
PNP Safe Operating Area



Transient Thermal Impedance



Derating Curve



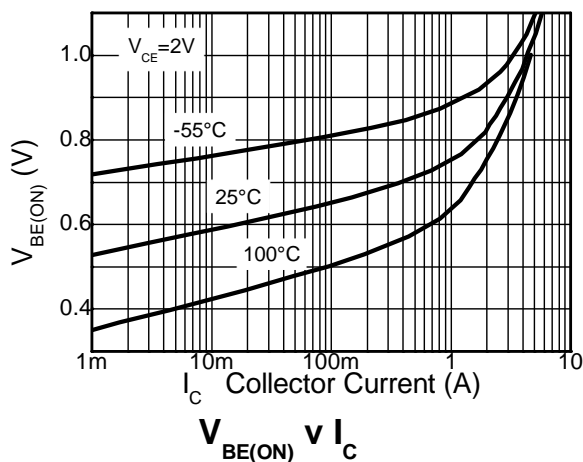
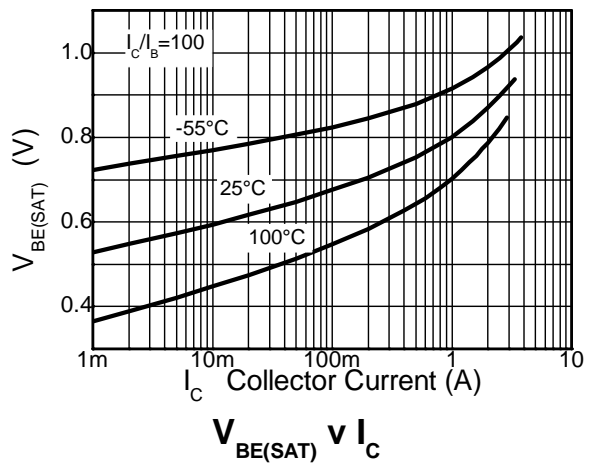
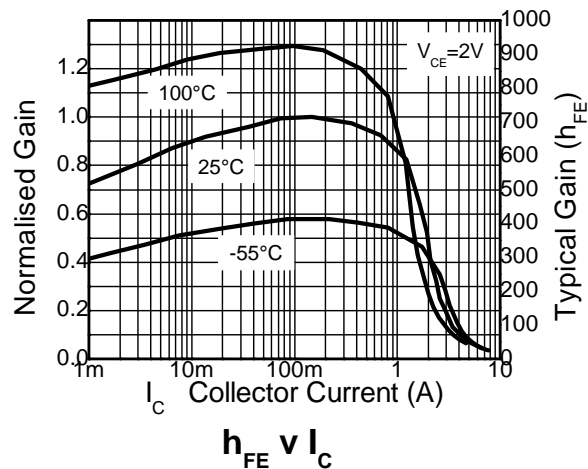
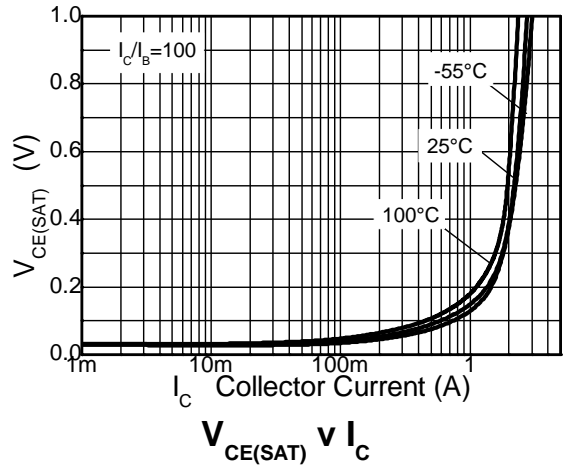
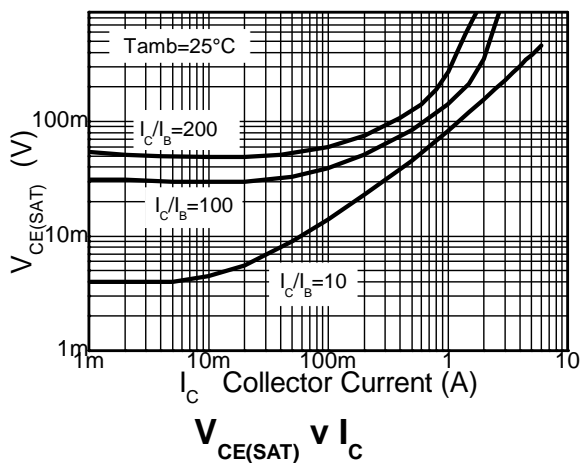
Pulse Power Dissipation

NPN - Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	45	—	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	45	—	—	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	—	—	V	I _E = 100μA
Collector Cut-Off Current	I _{CBO}	—	—	100	nA	V _{CB} = 35V
Emitter Cut-Off Current	I _{EBO}	—	—	100	nA	V _{EB} = 6V
DC Current Transfer Static Ratio (Note 9)	h _{FE}	500	—	—	—	I _C = 100mA, V _{CE} = 2V
		400	—	—		I _C = 1A, V _{CE} = 2V
		150	—	—		I _C = 2A, V _{CE} = 2V
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	—	—	100	mV	I _C = 100mA, I _B = 0.5mA
		—	—	500		I _C = 1A, I _B = 5mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	—	—	900	mV	I _C = 1A, I _B = 10mA
Base-Emitter Turn-on Voltage (Note 9)	V _{BE(on)}	—	—	900	mV	I _C = 1A, V _{CE} = 2V
Transitional Frequency (Note 9)	f _T	150	—	—	MHz	I _C = 50mA, V _{CE} = 5V, f = 50MHz
Input Capacitance	C _{ibo}	—	200	—	pF	V _{EB} = 0.5V, f = 1MHz
Output Capacitance	C _{obo}	—	16	—	pF	V _{CB} = 10V, f = 1MHz
Switching Time	t _{on}	—	33	—	ns	V _{CC} = 10V, I _C = 500mA, I _{B1} = 50mA, I _{B2} = 50mA
	t _{off}		1,300		ns	

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

NPN – Typical Electrical Characteristics

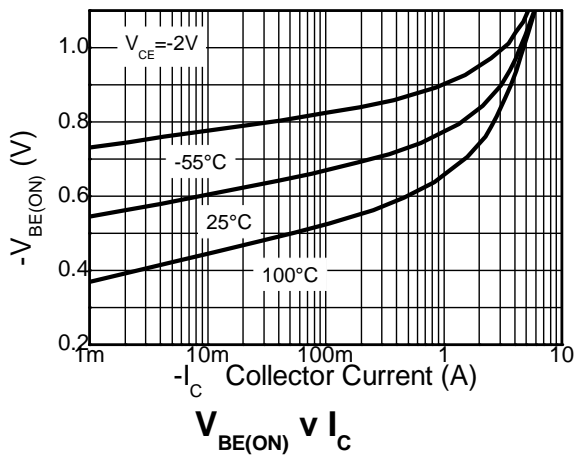
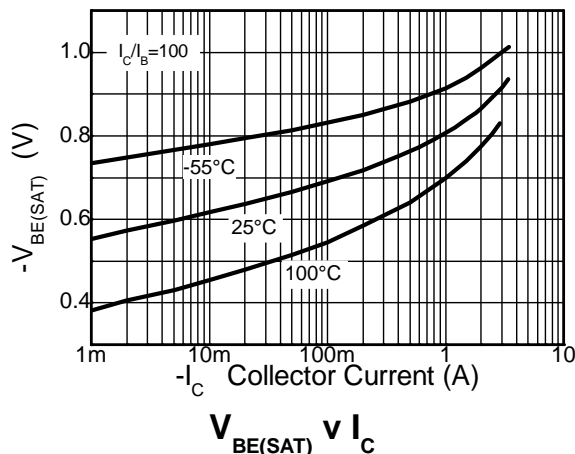
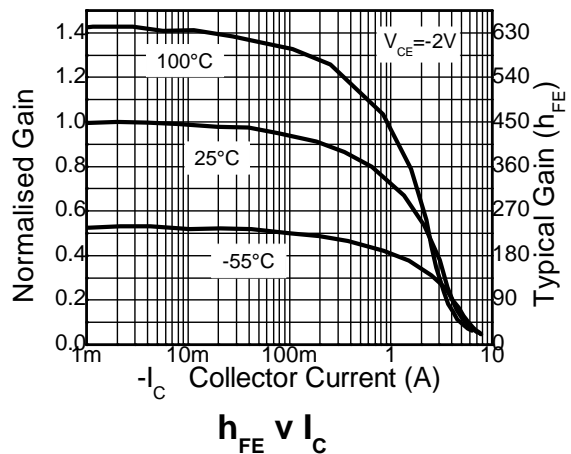
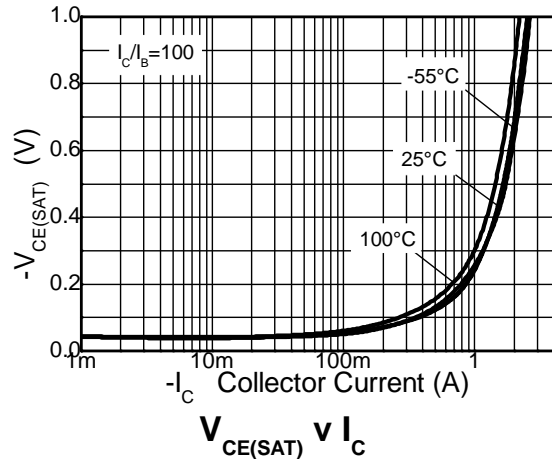
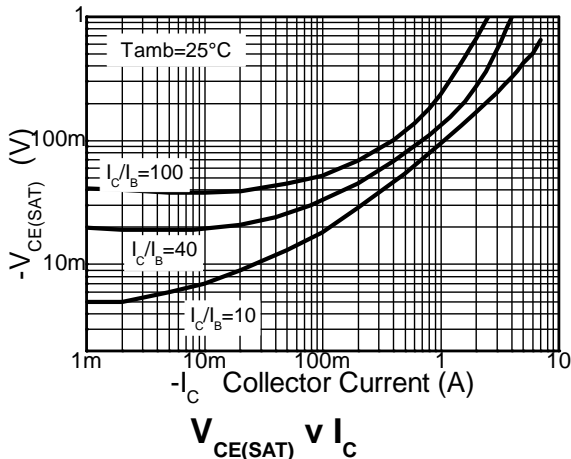


PNP - Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-50	—	—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-40	—	—	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	—	—	V	I _E = -100μA
Collector Cut-Off Current	I _{CBO}	—	—	-100	nA	V _{CB} = -30V
Emitter Cut-Off Current	I _{EBO}	—	—	-100	nA	V _{EB} = -6V
DC Current Transfer Static Ratio (Notes 9)	h _{FE}	300	—	800	—	I _C = -10mA, V _{CE} = -2V
		250	—	—		I _C = -500mA, V _{CE} = -2V
		200	—	—		I _C = -1A, V _{CE} = -2V
		150	—	—		I _C = -2A, V _{CE} = -2V
Collector-Emitter Saturation Voltage (Notes 9)	V _{CE(sat)}	—	—	-250 -450 -750	mV	I _C = -500mA, I _B = -5mA I _C = -1A, I _B = -10mA I _C = -2A, I _B = -50mA
Base-Emitter Saturation Voltage (Notes 9)	V _{BE(sat)}	—	—	-1,000	mV	I _C = -1A, I _B = -10mA
Base-Emitter Turn-on Voltage (Notes 9)	V _{BE(on)}	—	-750	—	mV	I _C = -1A, V _{CE} = -2V
Transitional Frequency (Notes 9)	f _T	100	—	—	MHz	I _C = -50mA, V _{CE} = -5V, f = 50MHz
Input Capacitance	C _{ibo}	—	225	—	pF	V _{EB} = -0.5V, f = 1MHz,
Output Capacitance	C _{obo}	—	24	—	pF	V _{CB} = -10V, f = 1MHz,
Switching Time	t _{on}	—	35	—	ns	V _{CC} = -10V, I _C = -500mA, I _{B1} = -50mA, I _{B2} = -50mA
	t _{off}		600		ns	

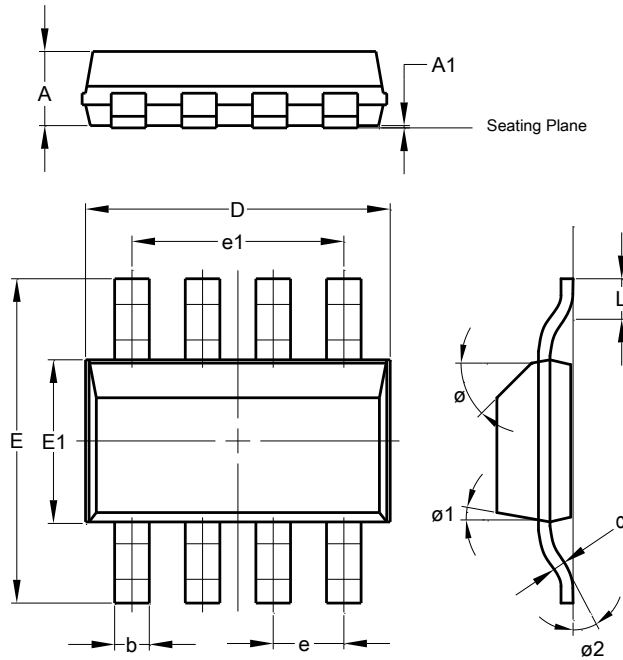
Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

PNP – Typical Electrical Characteristics



Package Outline Dimensions

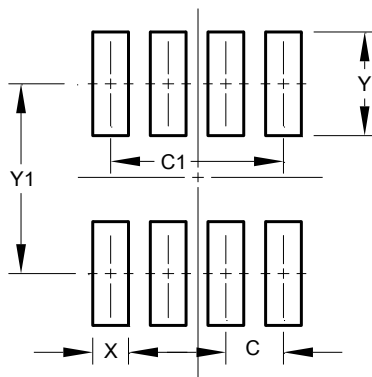
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SM-8			
Dim	Min	Max	Typ
A	--	1.70	1.60
A1	0.02	0.10	0.04
b	0.70	0.90	0.80
c	0.24	0.32	0.28
D	6.30	6.70	6.60
e	1.53 REF		
e1	4.59 REF		
E	6.70	7.30	7.00
E1	3.30	3.70	3.50
L	0.75	1.00	0.90
Ø	-	-	45°
Ø1	-	15°	-
Ø2	-	-	10°
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
C	1.52
C1	4.6
X	0.95
Y	2.80
Y1	6.80

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